



## Silver Sintering in Diversified Applications

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## Agenda

- Introduction of Heraeus
- Why sintering is needed
- Materials and Processes
- Sintering in Power Electronic Modules
- Sintering in Discretes
- Sintering in Power Amplifiers
- Summary

## Who We Are

- A globally active material technology Group
- Family-owned for over 160 years
- We create high value solutions for our customers and substantially strengthen their competitiveness
- We are organized in 11 Global Business Units
- Over 12,591 employees at over 100 sites in 38 countries
- 2014 product revenue: €3,4 billion
- 2014 precious metals trading revenue: €12,2 billion



Headquarter Hanau



Regional Headquarter Shanghai



Buford USA

## The Markets

We are active in global markets characterized by a clear differentiation lasting growth and attractive returns

Our ideas are focused on themes such as:



ENVIRONMENT



RENEWABLE  
ENERGY



HEALTH CARE



MOBILITY



INDUSTRIAL  
APPLICATIONS



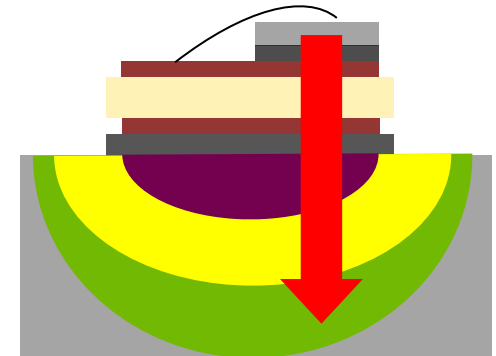
ELECTRONICS



Why sintering is needed?

## Trends in Electronic Packages

- **Longer Lifetime**
  - Automotive electronics; Systems, difficult to access
- **Miniaturization**
  - Restricted installation volume
  - Cost reduction (reduction of die and substrate size)
- **Increase of power density and operation temperature**
  - Accelerated aging of die contact materials
- **Reduction of manufacturing Costs**
  - Minimize process costs (no cleaning after processing)
  - Lower material costs (by increase of power density)
- **Lead Free Electronics**

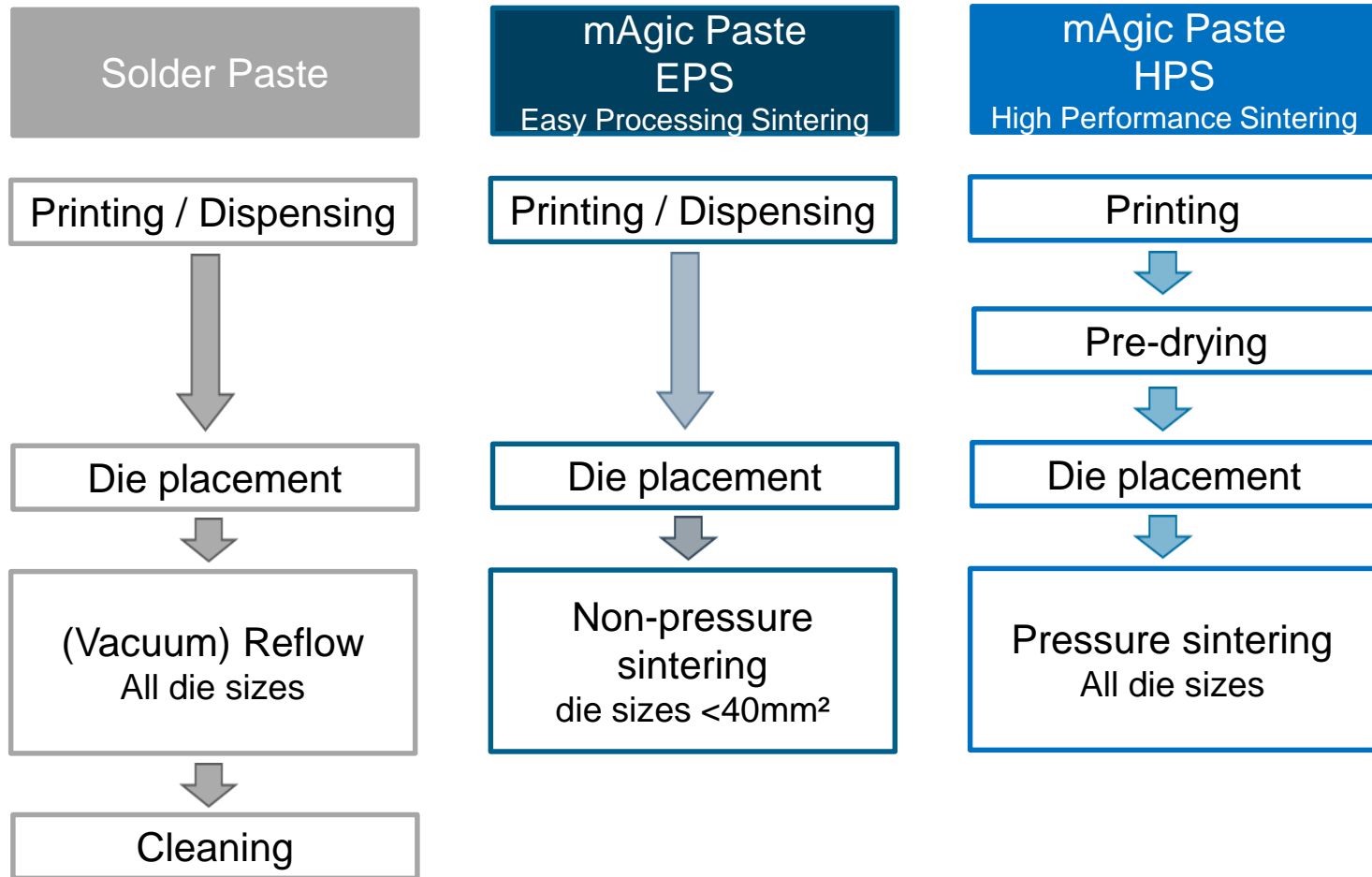




# mAgic Sintering Materials, Processes, Applications



# Processes





# Comparison of Material Properties

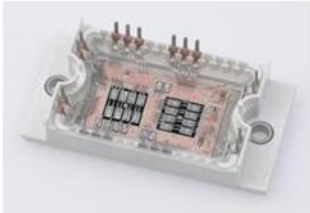


Material properties	SnAg3.5 Solder	mAgic Paste LTS295-Series EPS	mAgic Paste ASP016/043 HPS
Electrical resistivity [mΩ·cm]	<b>0.01 - 0.03</b>	<b>≤ 0.008</b>	<b>≤ 0.008</b>
Thermal conductivity [W/m·K]	<b>20 - 50</b>	<b>&gt;100</b>	<b>&gt; 200</b>
CTE [ppm/K] (below/above T <sub>g</sub> )	25 - 30	19	19
E-Modulus @ 25°C [GPa]	~ 30	~ 25	~ 50
Shear strength [N/mm <sup>2</sup> ]	~ 40	≥ 10	≥ 10
Process temperature [°C]	<b>230-260</b>	<b>≥ 230</b>	<b>≥ 230</b>
Residue free	<b>No</b>	<b>Yes</b>	<b>Yes</b>



# mAgic Sinter Applications

## Power Modules



- **Highest Life Time**
- **High Operation Temperature**

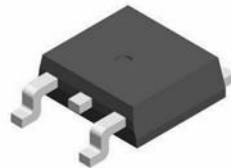
- *Highest Life Time*
- *High Operation Temperature*

- *High Operation Temperature (<400°C) Interconnect Material*

- *Die Attach for Wide Band Gap Semiconductors*
- *Interconnect Material for High Temperature Electronics*

High Temp Electro

## Discretes



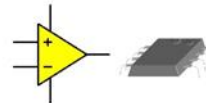
- **Lead Free**
- **Melting Point >260°C**
- **MSL 1 Proven**

- *High Thermal Conductivity >100W/mK*
- *High Electrical Conductivity >10MS*
- *Low Processing Temperature ≤ 200°C*

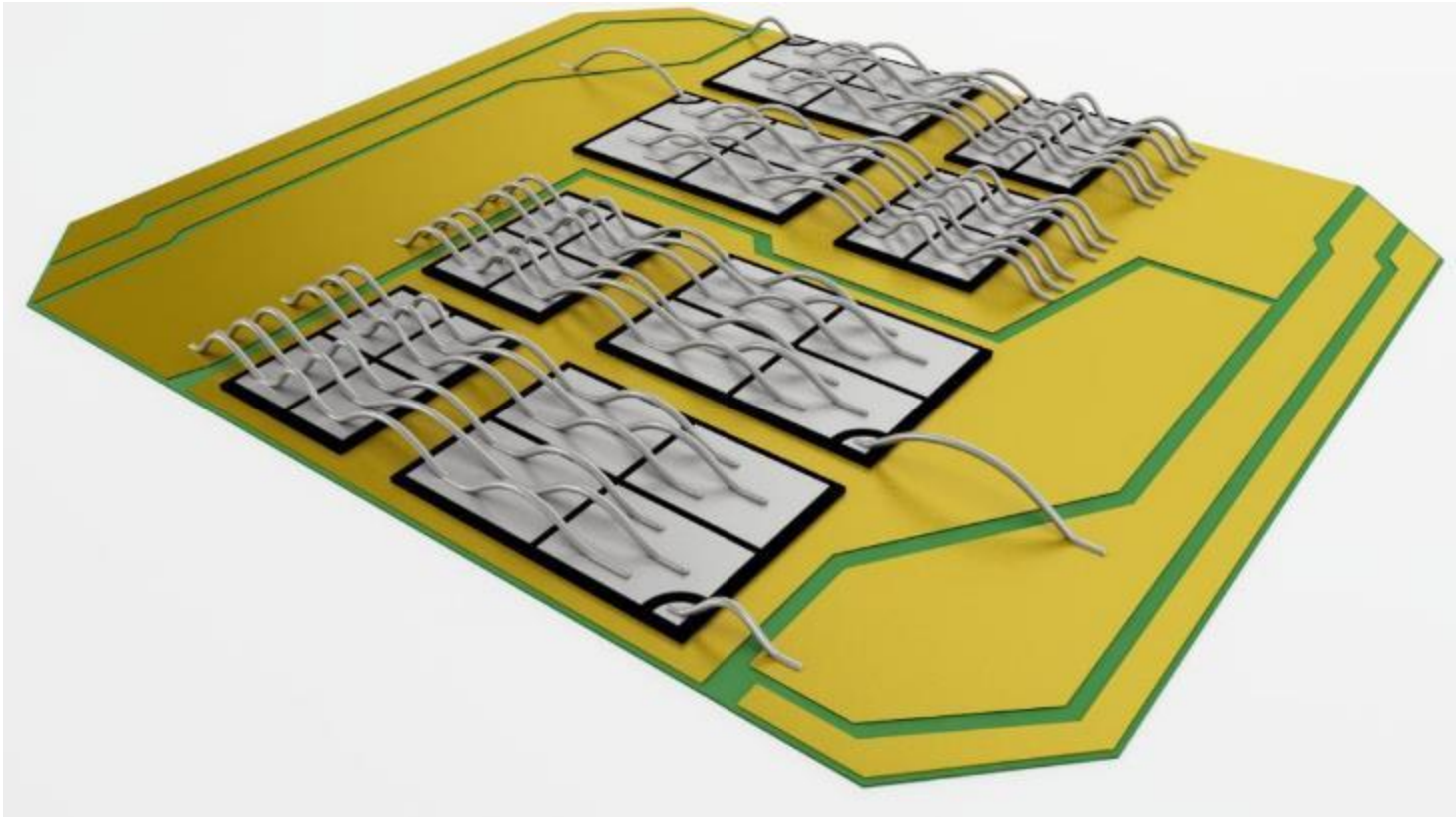
- *High Electrical Conductivity*
- *Improvement of Device Performance*
- *Solder Replacement*

Increase of Performance and Power Density

## Power Amplifier

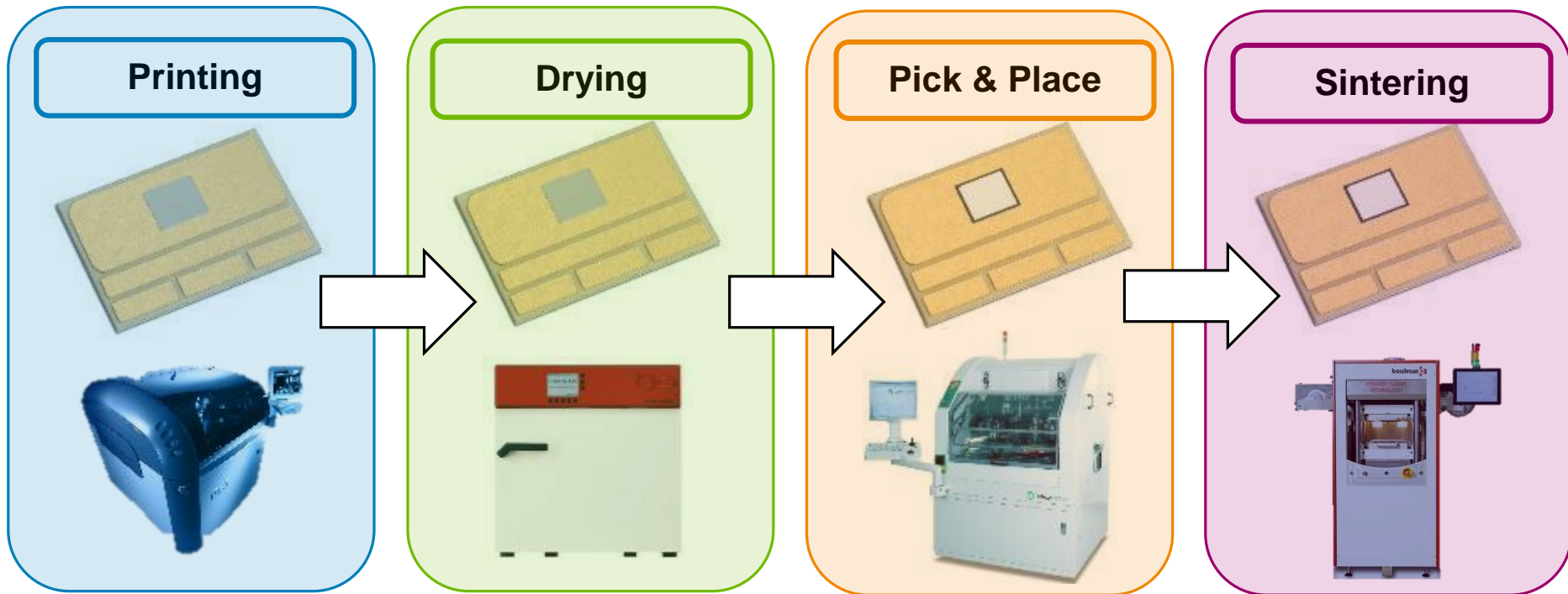


- **High Thermal Conductivity >100W/mK**
- **High Electrical Conductivity >10MS**
- **Low Processing Temperature ≤ 200°C**



## mAgic Sinter Materials in Power Electronic Modules

# HPS Process



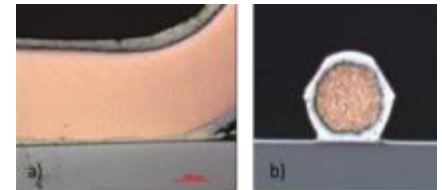
# Benchmark Wire Bonding and Die Attach Material – Power Cycling Test Package

## Conventional **DCB** package:

- DCB : bare Cu for solder, NiAu metallization for mAgic product
- Diode: Infineon: 8.15 mm x 9 mm diode, NiAg backside metallization, thickness: 120  $\mu\text{m}$

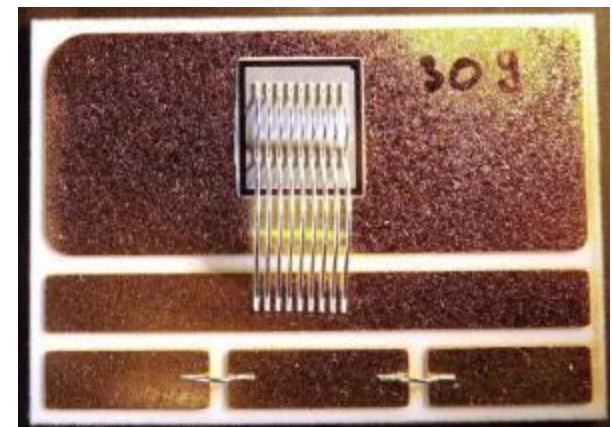
## Tested Materials

- Wire Bond Materials     Al-Wire, 300 $\mu\text{m}$  vs. AlCu-wire, 300 $\mu\text{m}$
- Die Attach Material     SnAg3.5 Solder vs. mAgic Sinter Paste

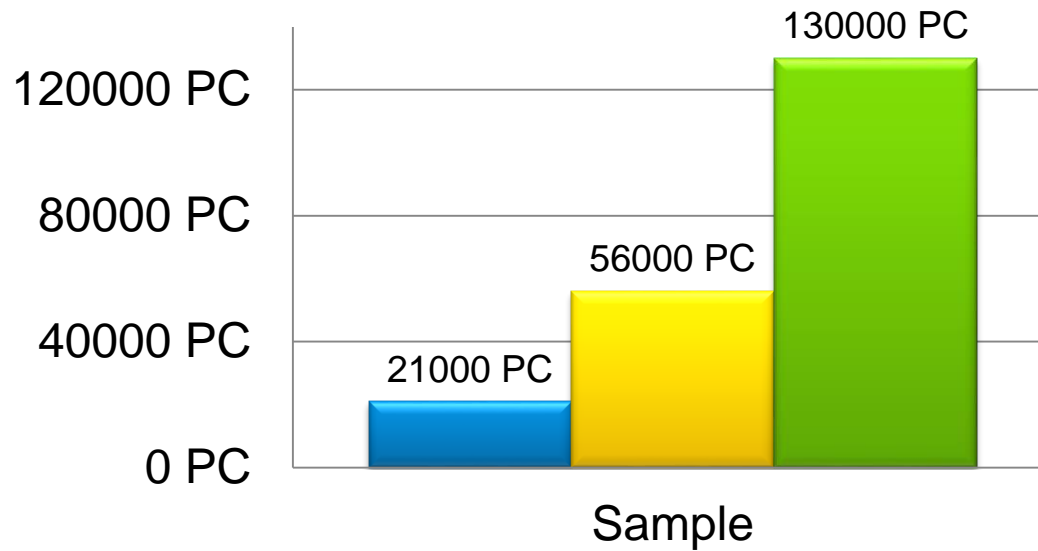


## Active power cycle test Parameter

- $t_{\text{on}}=t_{\text{off}}=15\text{s}$
- $T_{\text{min}}=40^{\circ}\text{C}$
- $\Delta T=110^{\circ}\text{C}$



## Power Cycling Capabilities

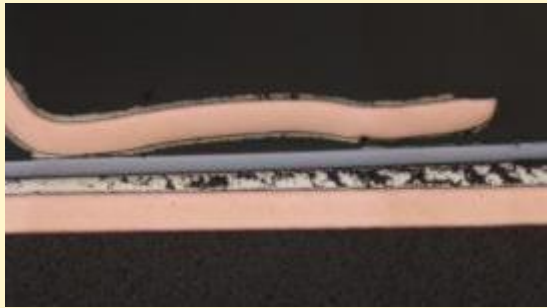


- Solder w/ Al wire
- Solder w/ CucorAl Wire
- Sinter layer w/ CucorAl Wire

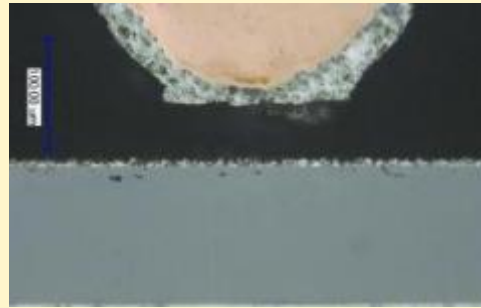
- Soldered module failed after 56,000 cycles
- Test of sintered module stopped after 130,000 cycles
- Improvement of life time >2.5 times

# Soldered Modules Bonded using AlCu Wires at End of Life

## Soldered Module with AlCu-Wire after 56.000 Power Cycles



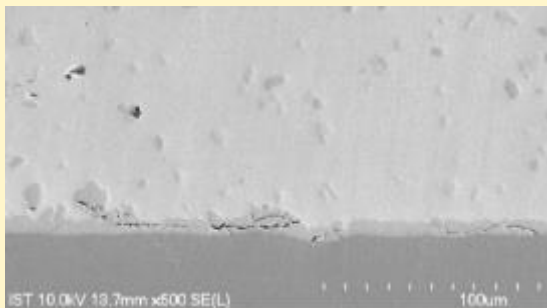
Overview Picture



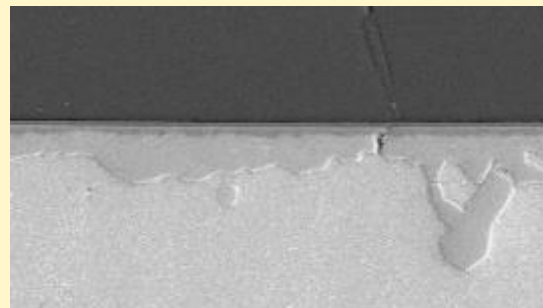
Bond Lift on Chip



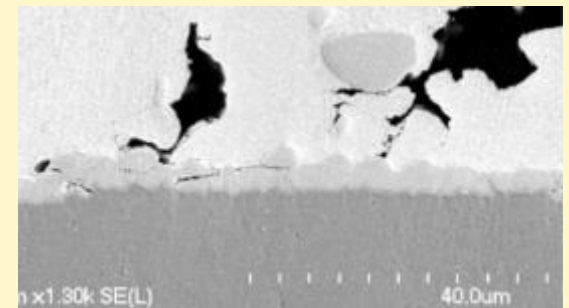
Die Attach Layer Center



SEM DA Layer Center



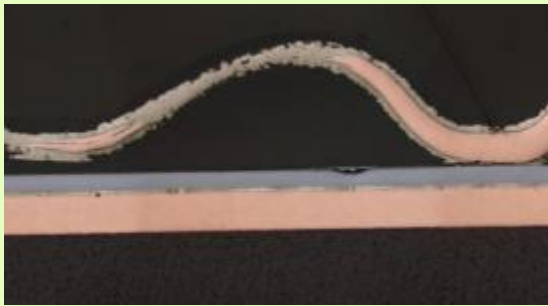
SEM DA Layer Center



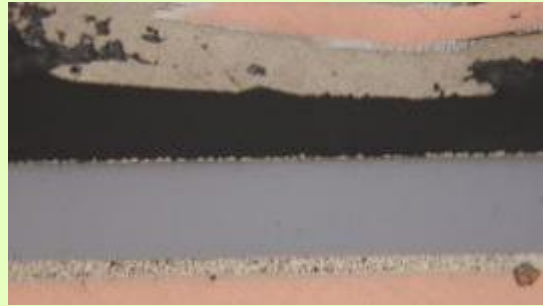
SEM DA Layer Corner



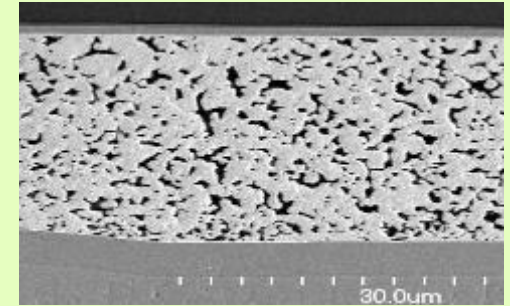
# Sintered Modules Bonded using AlCu Wires at 130000 Power Cycles



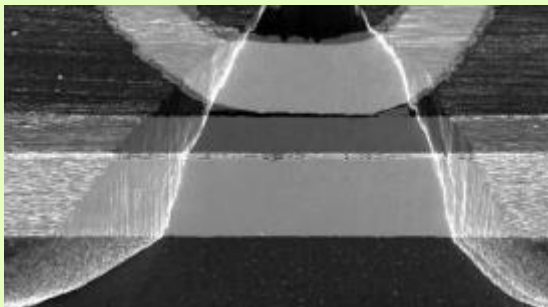
Overview Picture



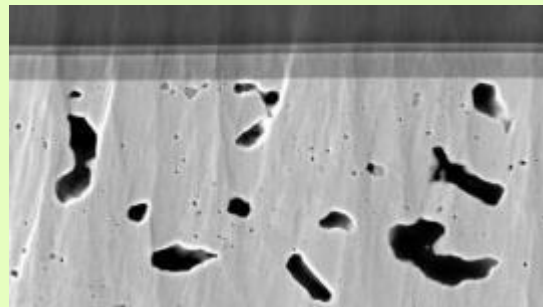
Bond Lift on Chip



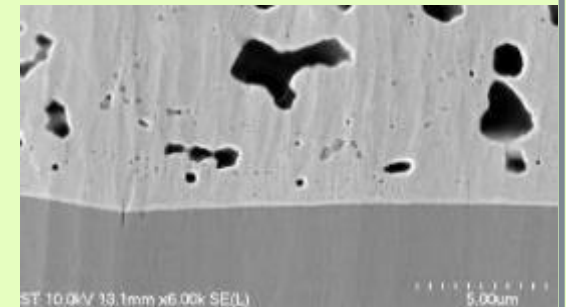
Die Attach Layer



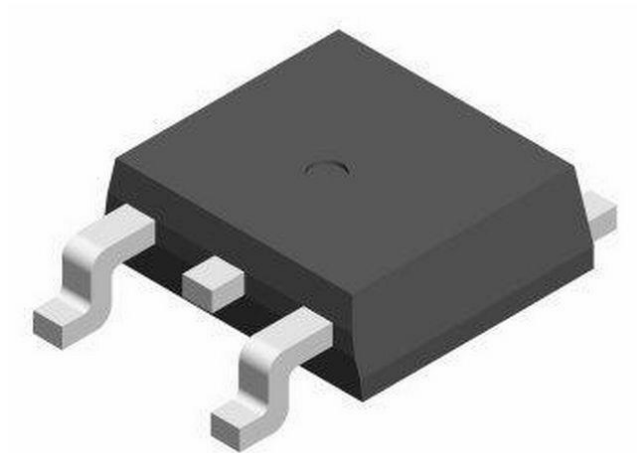
SEM DA Layer Center



SEM DA Layer Corner



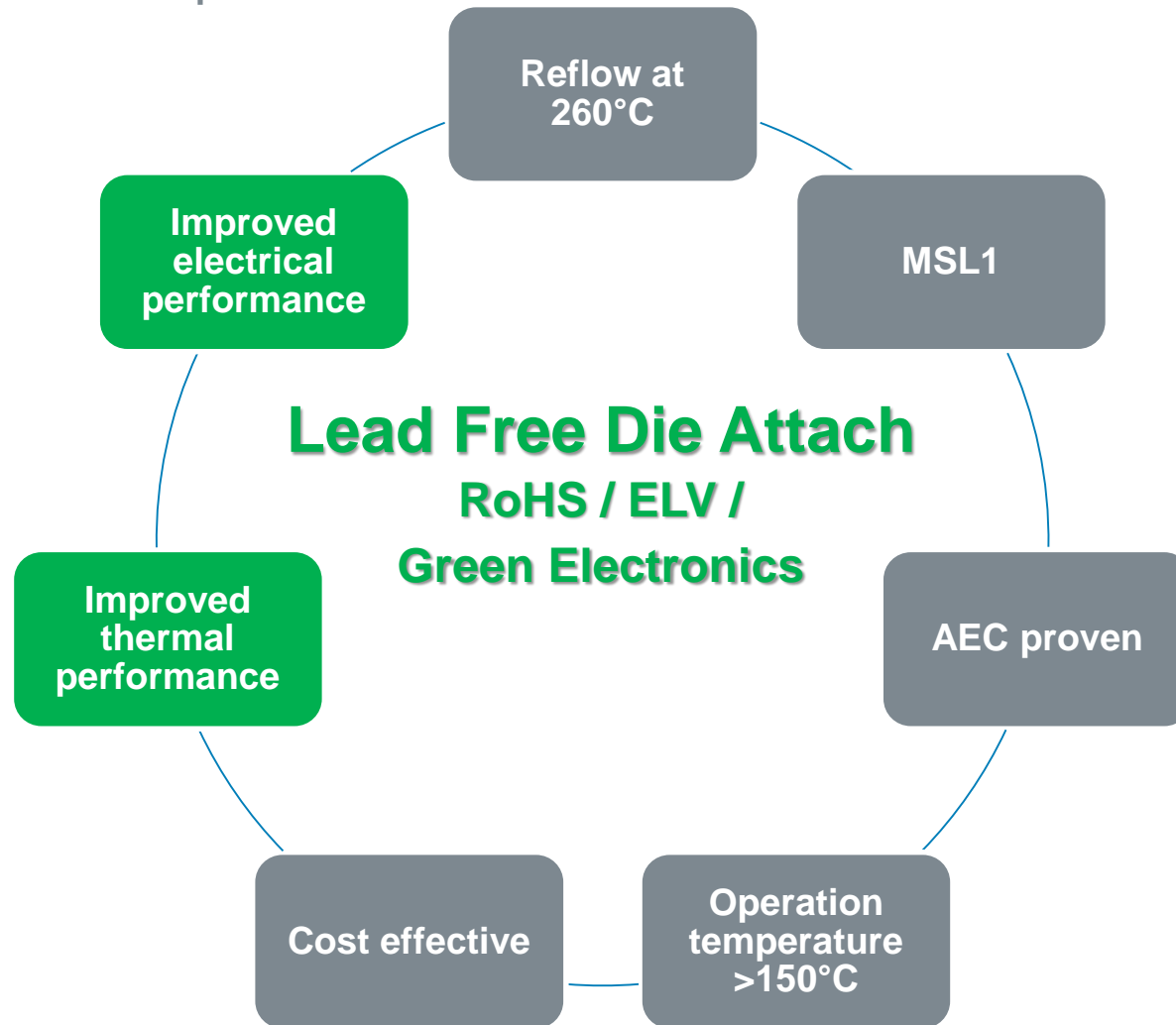
SEM DA Layer Corner



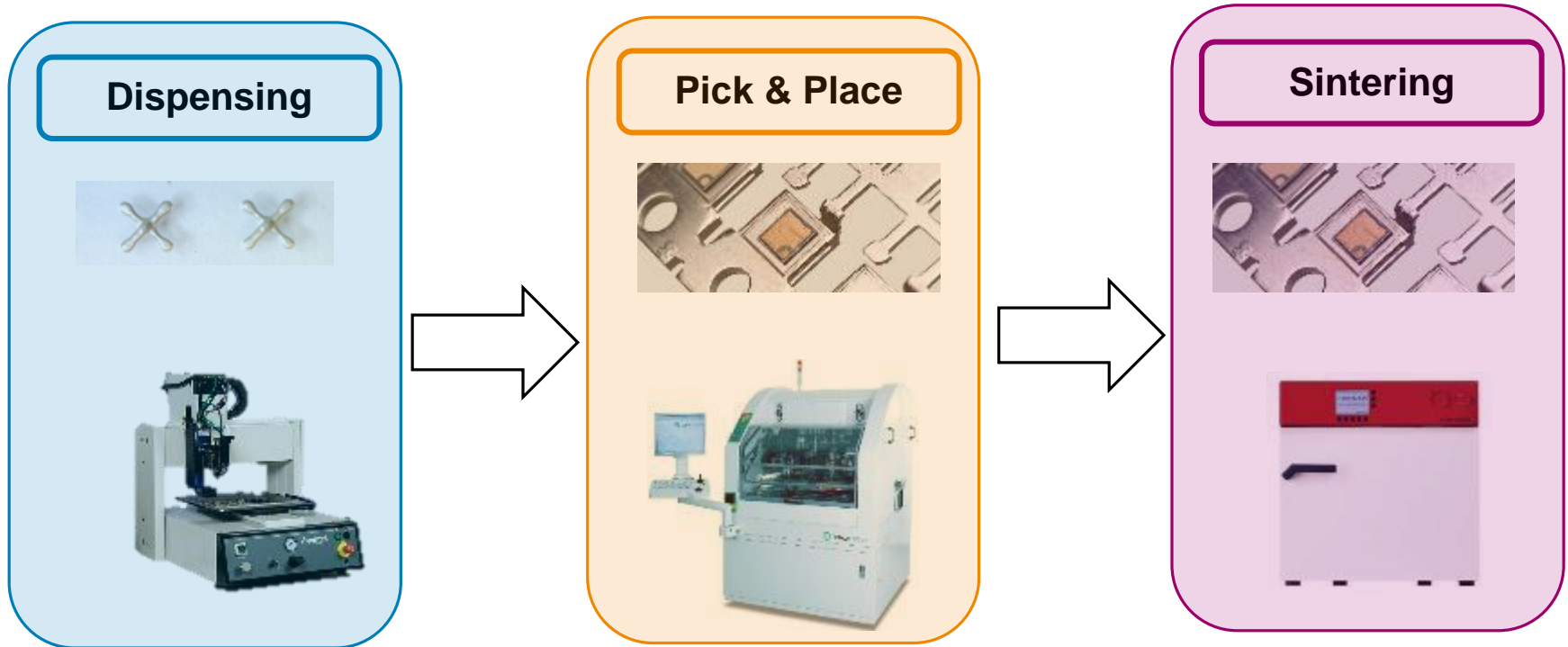
## mAgic Sintering Material in Discretes

# Sintering as Die Attach Technology

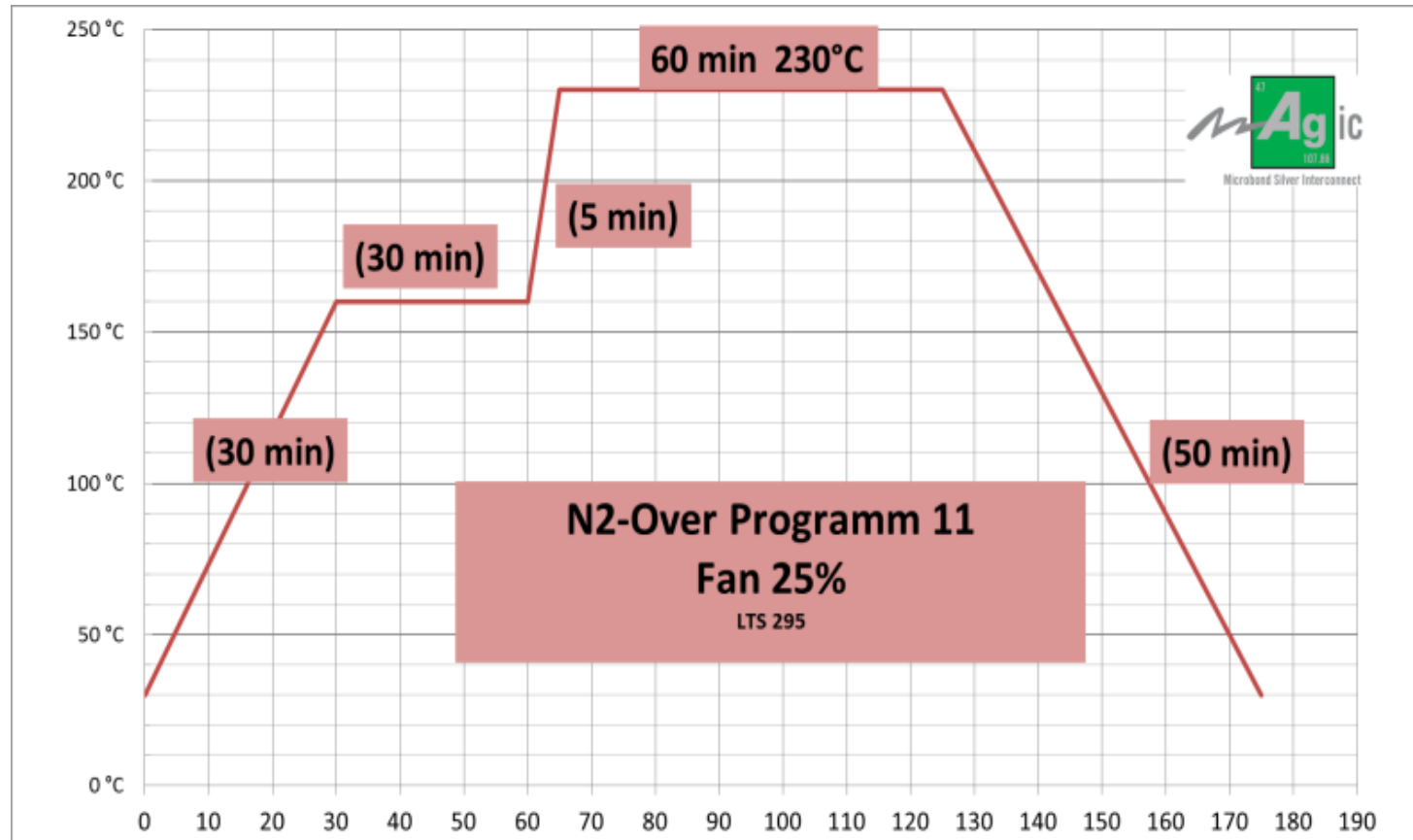
## Motivation and Requirements



# Pressure - Free Sintering Process



## Example of Sintering Profile



# Reliability Test on D2Pak Setup

## ■ D2Pack Power MOSFET package (automotive part)

- Die Size is 4.3mm x 6.1mm
- Paddle size is 8.53 mm x 5.10 mm; Ag Spot Plating for paste
- Die Attach materials: Sinter Paste ASP295

## ■ Reliability tests performed

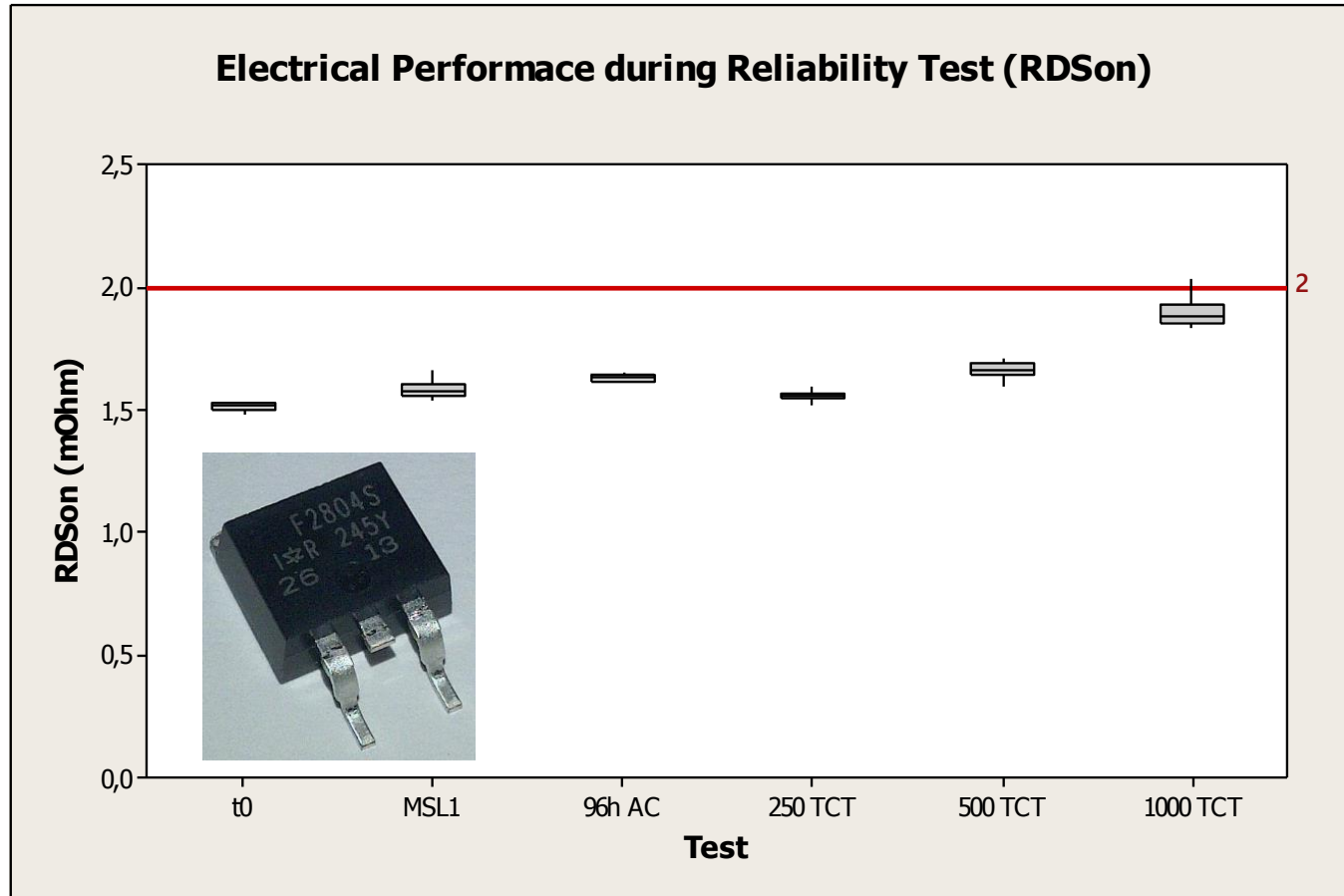
- MSL1 3 times reflow after 168h 85/85 storage
- Auto Clave 96h @ 121°C, 1 bar and 100% r-h.
- Temperature Cycle Test -55/+150°C

## ■ Test methods

- $R_{DSon}$  measurement
- Inspection of X-section

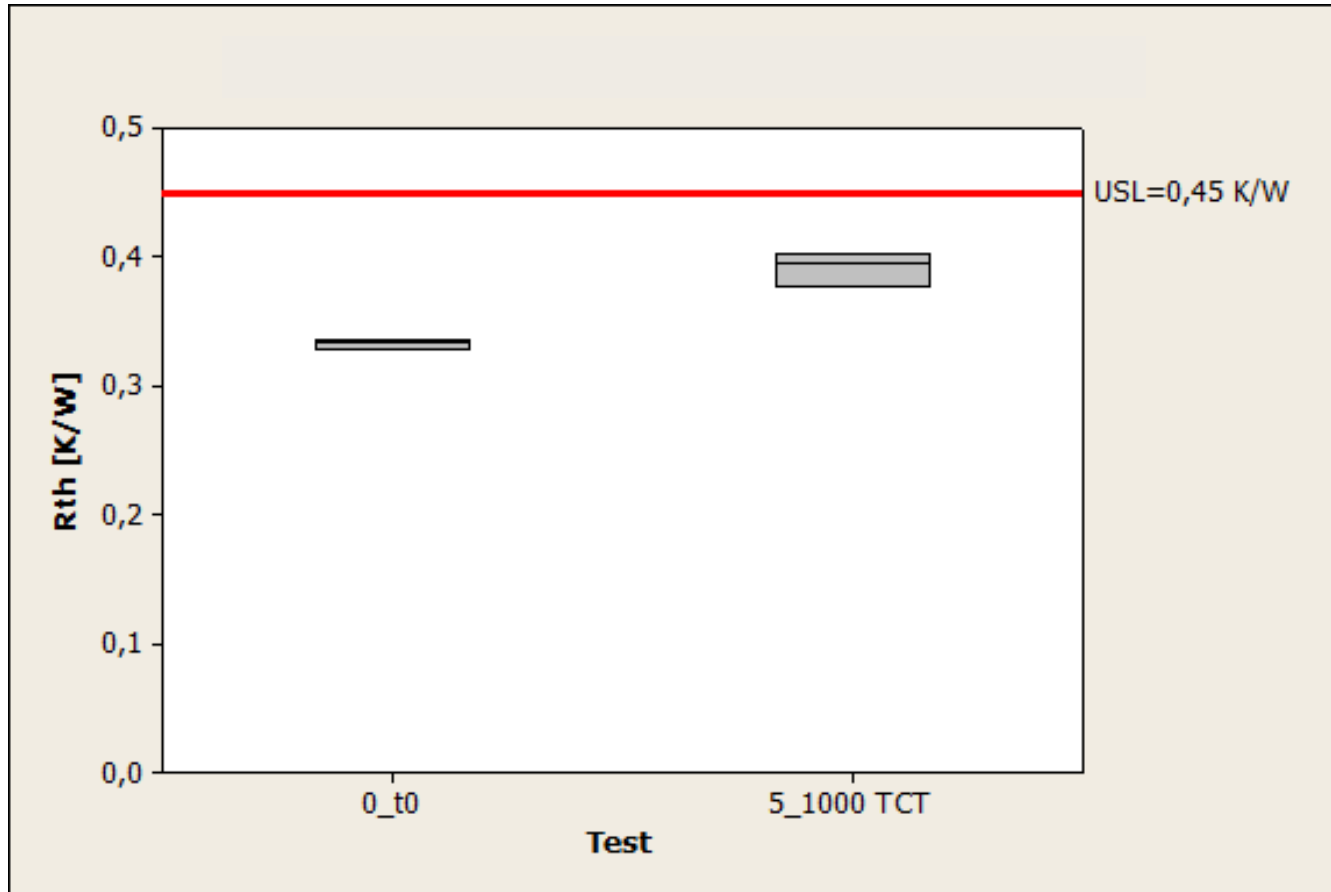
# ASP 295 in D2Pak

## $R_{D\text{Son}}$ Test Result

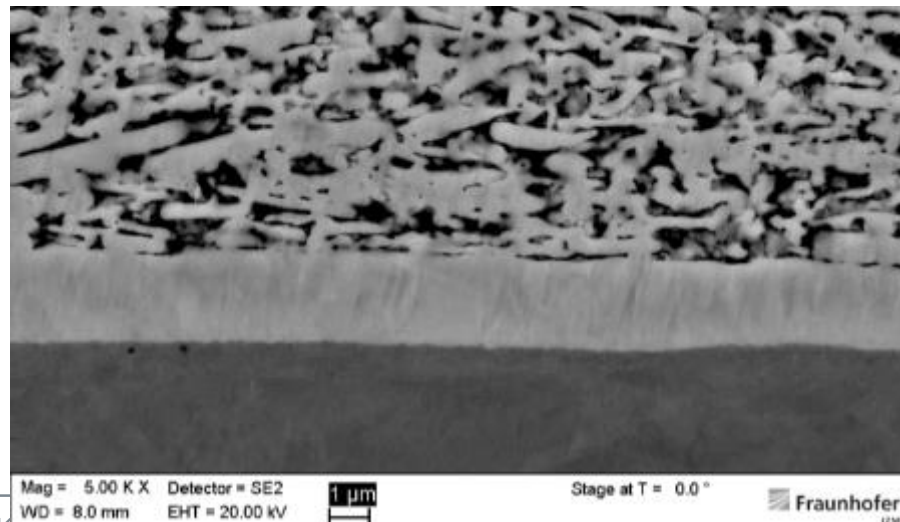
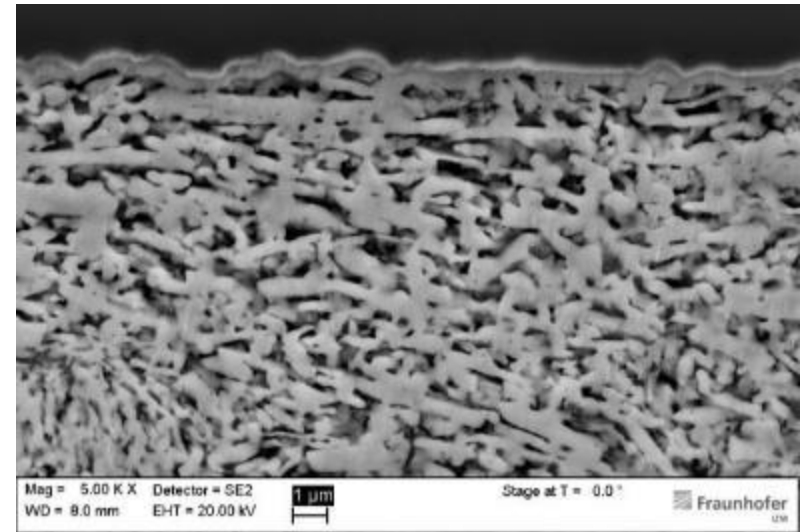
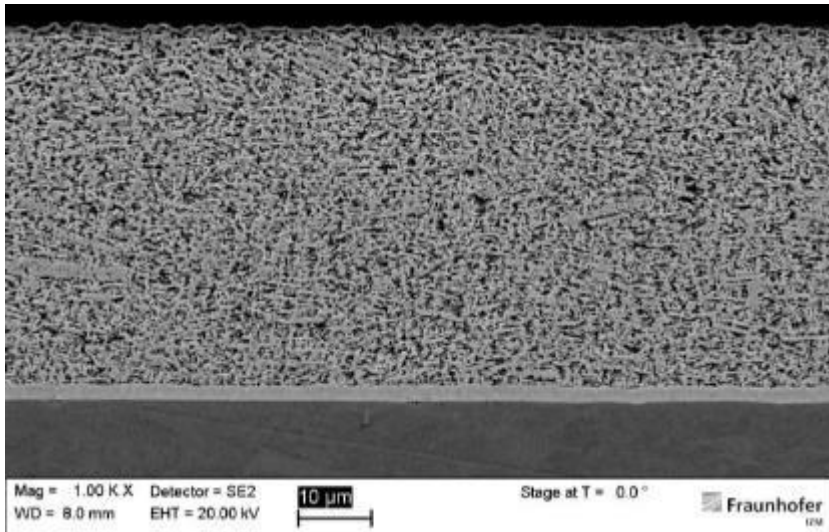




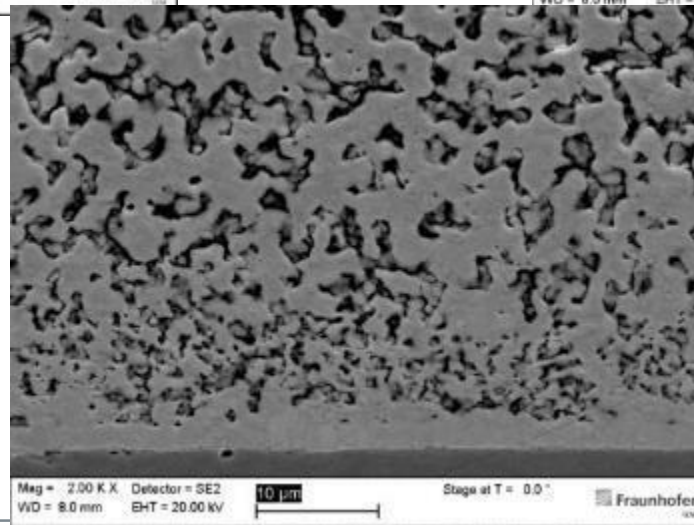
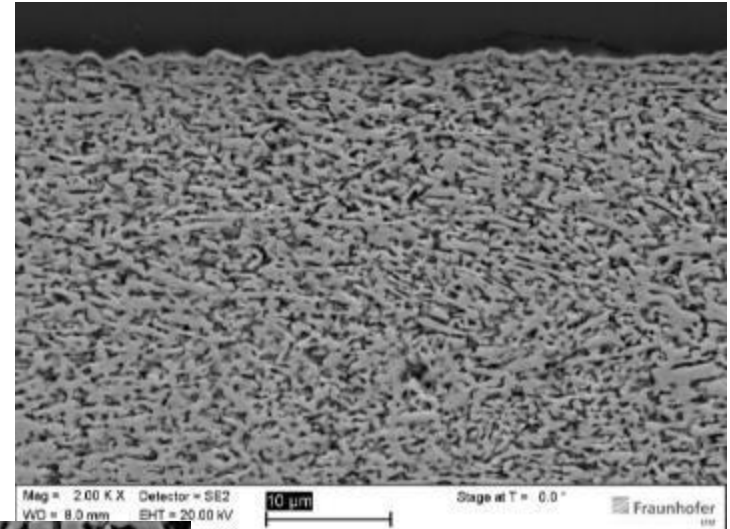
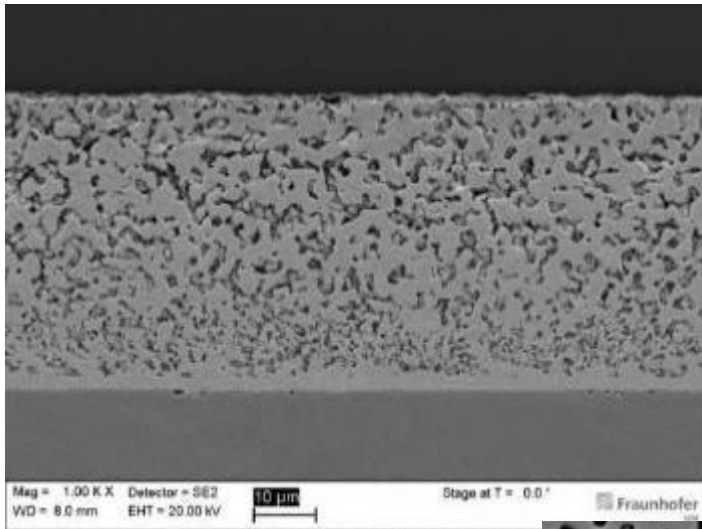
# ASP 295 in D2Pak $R_{th}$ Test Result

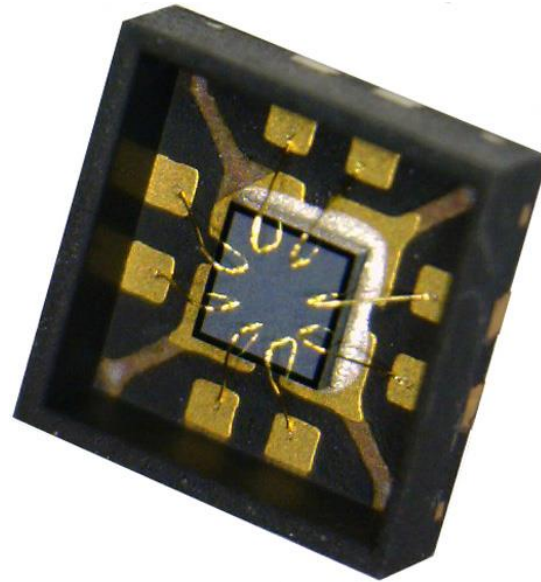


# LTS295-01P2 Initial



## LTS295-01P2 1000 TCT -55/+150°C

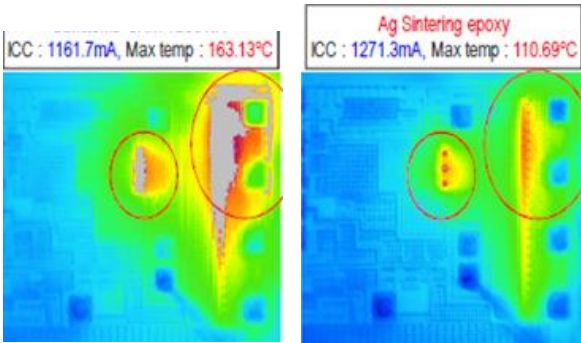
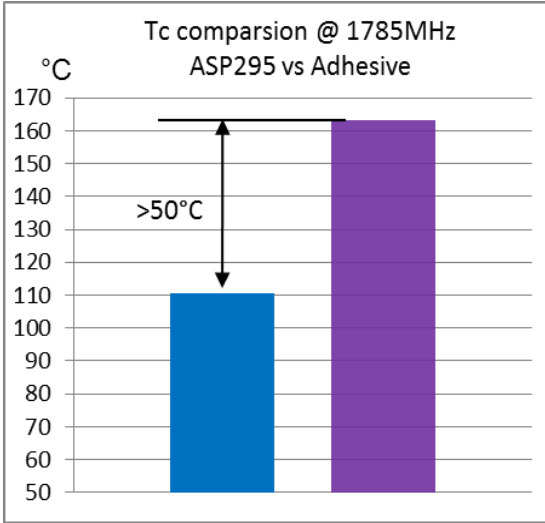




# mAgic Sintering Material for Power Amplifier on Organic Substrates

# Power Amplifier

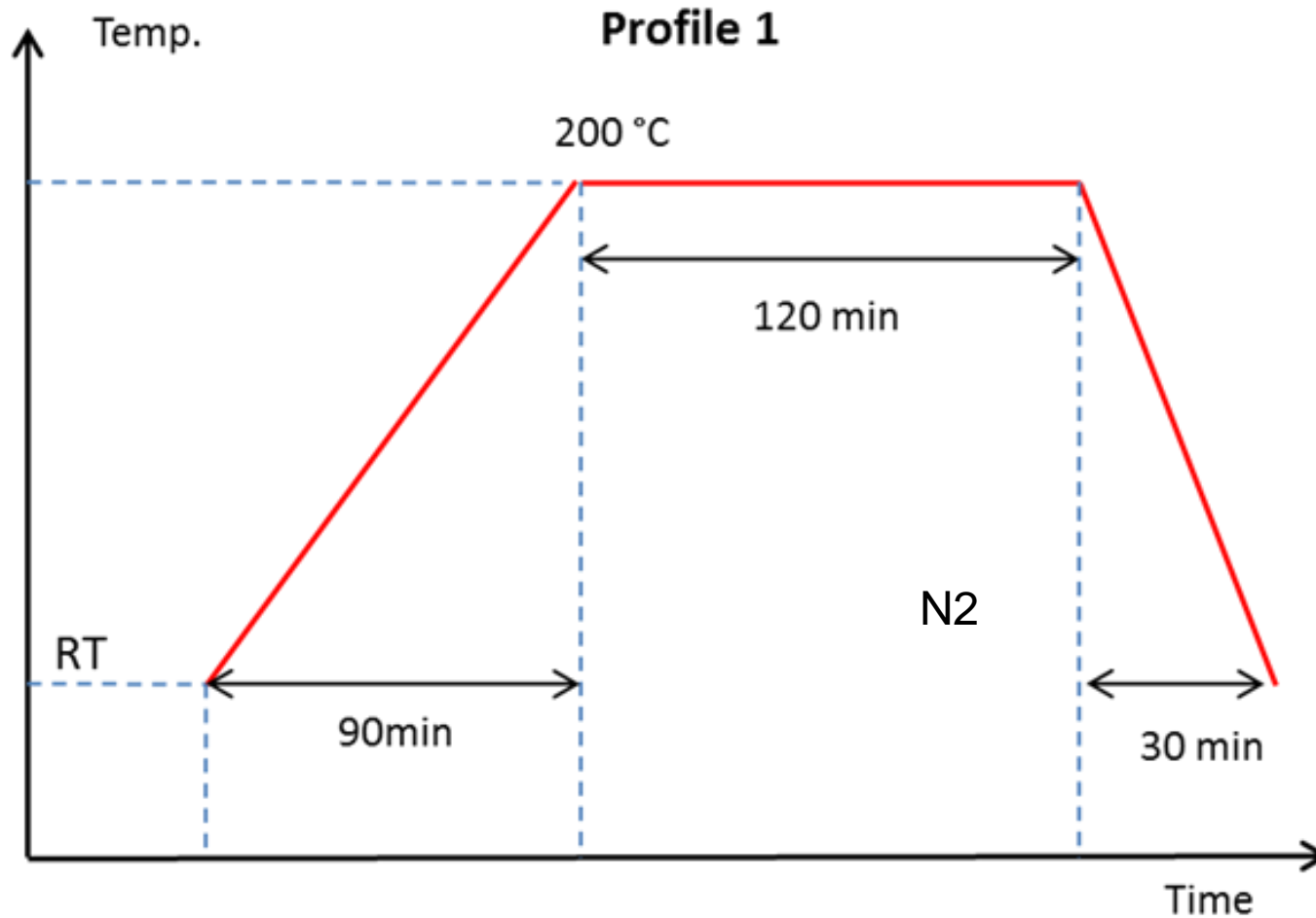
- PA Chips generating a lot of heat but getting less efficient if they are getting hotter
- This drives the need for higher thermal conductivity die attach materials
- mAgic sinter paste provides outstanding thermal conductivity between die and substrate
- Improved thermal conductivity of die attach material enable
  - Lower chip temperatures
  - Less power loss and longer battery life
  - Improved performance



	therm. enhanced Adhesive	ASP 295 (mAgic sinter paste)
Tc @848MHz	153,9	115,61
Tc @1785MHz	163,13	110,69

# Sinter Profile

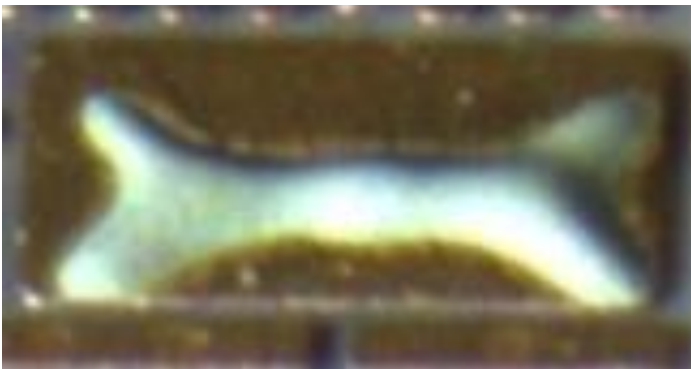
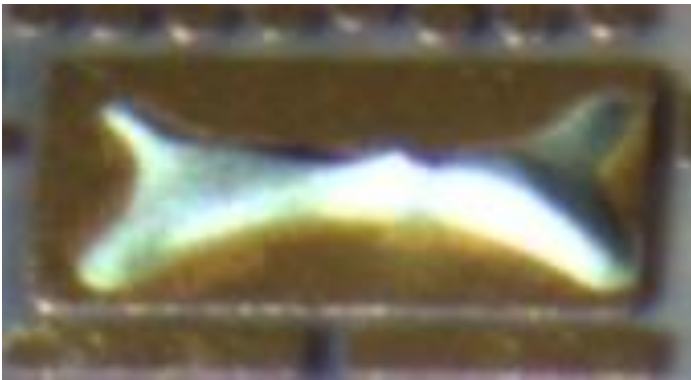
## Pressure Less Sintering EPS



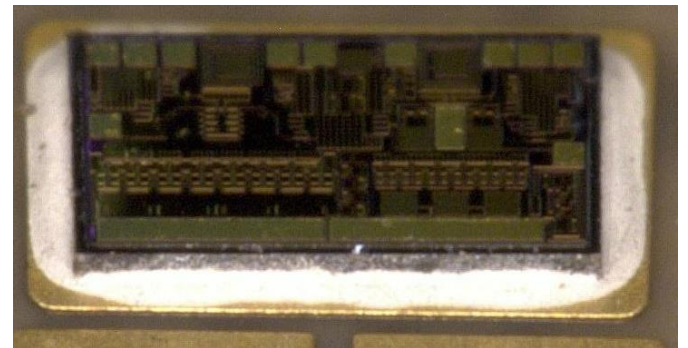
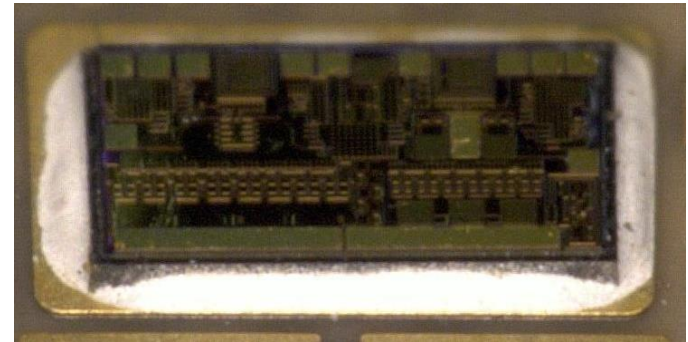


## Workability Results

Dispensing



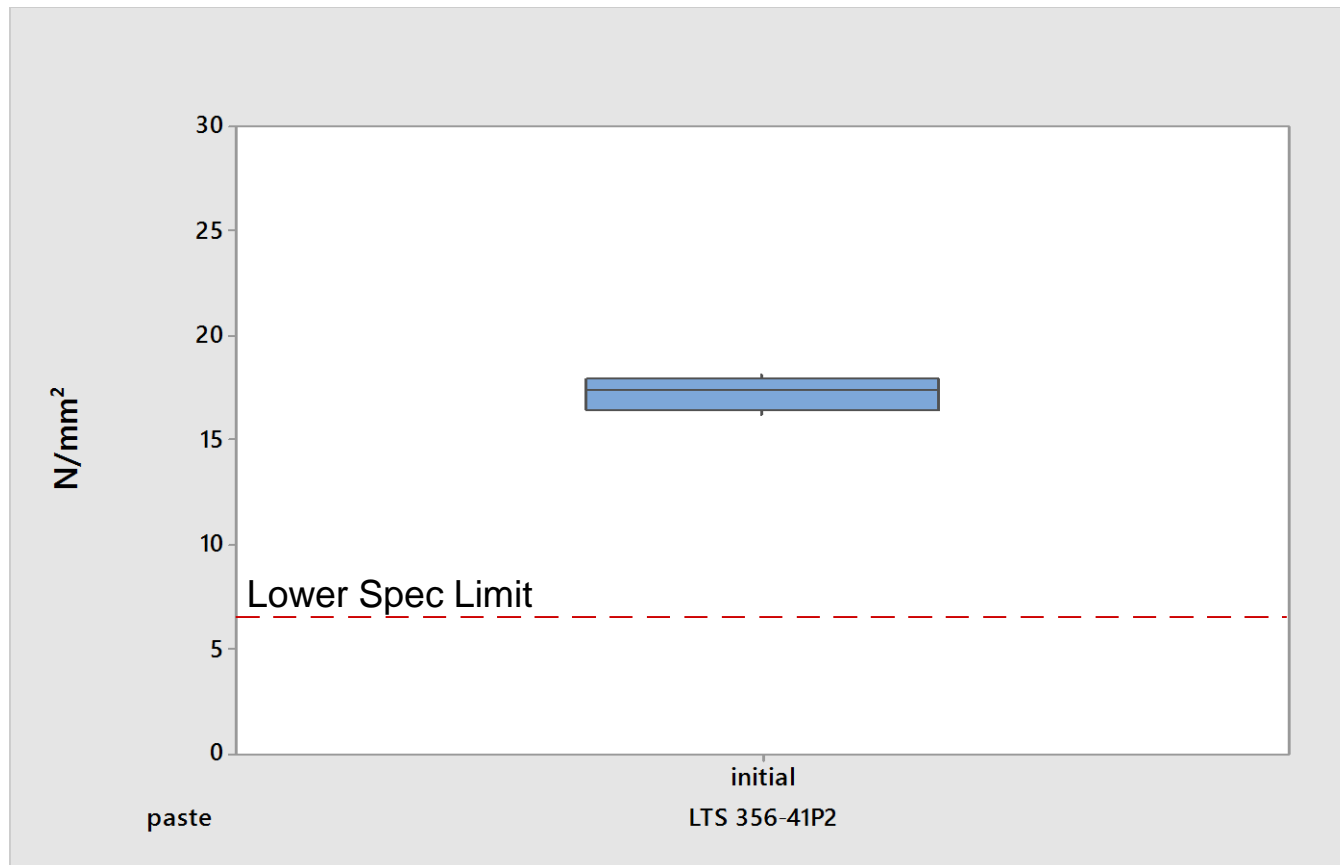
Die Attach





# Workability Results

## Die Shear

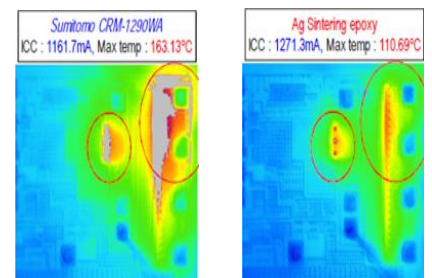




# Summary

## Summary

- Based on its unique properties and processing silver sintering allows a usage in different applications
- Due to its material performance, thermally, electrically and mechanically it works as enabler and booster if the system is matched
- Compared to solders a makeable increase in life time for of interconnects in power electronics modules will be achieved based on its mechanical stability and thermal conductivity
- For discrete power electronics it can be used as lead free die attach solution, easy in processing and providing the required thermal and mechanical stability for 2<sup>nd</sup> level interconnect
- In high power density application like power amplifier it allows a further increase of power density or increase in life time due to its exceptional thermal conductivity





Thank You!